	Application No.	Applicant(s)
Notice of Allowability	10/650,234	GUNN ET AL.
	Examiner	Art Unit
	PHAN T.H. PALMER	2874
The MAILING DATE of this communication at All claims being allowable, PROSECUTION ON THE MERITS herewith (or previously mailed), a Notice of Allowance (PTOL NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATEN of the Office or upon petition by the applicant. See 37 CFR 1	S IS (OR REMAINS) CLOSED in -85) or other appropriate commu IT RIGHTS. This application is su	this application. If not included nication will be mailed in due course. THIS
1. This communication is responsive to <u>07/08/2005</u> .		
2. The allowed claim(s) is/are <u>1-23,47-69 and 93-109</u> .		
3.   The drawings filed on are accepted by the Exam	niner.	
<ul> <li>4. Acknowledgment is made of a claim for foreign priority a) All b) Some* c) None of the:</li> <li>1. Certified copies of the priority documents in the priority docu</li></ul>	have been received. have been received in Application	No
Applicant has THREE MONTHS FROM THE "MAILING DA' noted below. Failure to timely comply will result in ABANDO THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	TE" of this communication to file a DNMENT of this application.	a reply complying with the requirements
5. A SUBSTITUTE OATH OR DECLARATION must be su INFORMAL PATENT APPLICATION (PTO-152) which	ubmitted. Note the attached EXAI gives reason(s) why the oath or o	MINER'S AMENDMENT or NOTICE OF declaration is deficient.
6. ☐ CORRECTED DRAWINGS ( as "replacement sheets")  (a) ☐ including changes required by the Notice of Drafts  1) ☐ hereto or 2) ☐ to Paper No./Mail Date  (b) ☐ including changes required by the attached Examin Paper No./Mail Date  Identifying indicia such as the application number (see 37 CF each sheet. Replacement sheet(s) should be labeled as such 7. ☐ DEPOSIT OF and/or INFORMATION about the definition of the sheet is a such as the sheet is a such as the sheet is a such as the sheet.	person's Patent Drawing Review  ner's Amendment / Comment or i  FR 1.84(c)) should be written on the in the header according to 37 CFR eposit of BIOLOGICAL MATE	n the Office action of drawings in the front (not the back) of 1.121(d). RIAL must be submitted. Note the
attached Examiner's comment regarding REQUIREME	INT FOR THE DEPOSIT OF BIOL	LOGICAL MATERIAL.
Attachment(s) 1. ☑ Notice of References Cited (PTO-892)	E T Maria (C) C	man I Data at Amelia at a 1970 (70)
<ol> <li>Induce of References Cited (PTO-692)</li> <li>Induce of References Cited (PTO-</li></ol>		ormal Patent Application (PTO-152)
Information Disclosure Statements (PTO-1449 or PTO/S		fill Date mendment/Comment
Paper No./Mail Date	<u>_</u>	
Examiner's Comment Regarding Requirement for Depos  of Diplomical Material	<del>_</del>	statement of Reasons for Allowance
of Biological Material	9. 🗌 Other	Phan T. H. Palmer PHAN T. H. PALMER PRIMARY EXAMINER 08/02/2005

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## EXAMINER'S AMENDMENT Amot / PMP

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows: claims 24-46, 70-92, and 110-124 have been cancelled.

## **REASON FOR ALLOWANCE**

2. The following is an examiner's statement of reasons for allowance: the claims are allowable over prior art of record, because none of the references in alone or in combination discloses:

## An optoelectronic device on a substrate comprising:

- a waveguide comprising a slab of monocrystalline silicon on the substrate, a layer of dielectric material disposed on the slab, and a strip of polysilicon disposed on the layer of dielectric material;
- a plurality of doped regions in the slab of monocrystalline silicon, where at least first and second doped regions are formed in the slab of monocrystalline silicon, and
- a plurality of electrical contacts, where at least first and second electrical contacts are formed in respective first and second doped regions of the plurality

of doped regions in the slab of monocrystalline silicon, as discloses in claims 1, 47, and 93.

The underlined imitations are critically, since the optoelectronic device is improved: low loss signal, high yields and low fabrication cost and continuous process improvements.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

## **CONTACT INFORMATION**

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to PHAN T.H. PALMER whose telephone number is (571) 272-2354. The examiner can normally be reached on Monday to Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, RODNEY B. BOVERNICK can be reached on (571) 272-2344. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

PTHP 08/02/2005

PHAN T. H. PALMER PRIMARY EXAMINER